MSKSEMI















ESD

TVS

TSS

MOV

GDT

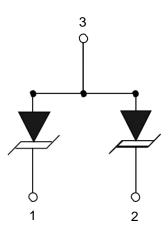
PLED

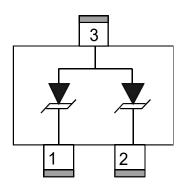
Broduct data sheet





SOT-23





Features

- 150 Watts peak pulse power (tp = $8/20\mu$ s)
- Bidirectional and unidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Low capacitance (C_j=100 pF typ.)
- Protection two data lines
- IEC 61000-4-2 \pm 20kV contact \pm 15kV air
- IEC 61000-4-4 (EFT) 40A(5/50ns)
- IEC 61000-4-5 (Lightning) 10A(8/20μs)

Mechanical Data

- SOT-23 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Applications

- Dataline
- Automatic Teller Machines
- Net works
- Power line



Absolute Maximum Rating

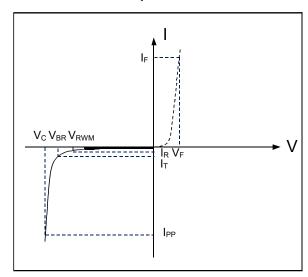
Rating	Symbol	Value	Units
Peak Pulse Power (t _p =8/20μs)	P _{PP}	150	Watts
Peak Pulse Current (t _p =8/20μs)(note1)	I_{pp}	10	A
ESD per IEC 61000-4-2(Air) ESD per IEC 61000-4-2 (Contact)	V _{ESD}	20 15	kV
Lead SolderingTemperature	T_{L}	260(10seconds)	$^{\circ}$
JunctionTemperature	TJ	-55 to + 125	$^{\circ}$
StorageTemperature	T_{stg}	-55 to + 125	$^{\circ}$

Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-OffVoltage	$V_{ m RWM}$				5	V
Reverse BreakdownVoltage	V_{BR}	I _T =1mA	6.0			V
Reverse LeakageCurrent	I_R	V _{RWM} =5V,T=25°C			1	μА
Peak Pulse Current	I_{PP}	tp =8/20μs			10	A
Clamping Voltage	X7.	I _{PP} =1A,t _p =8/20μs			10	V
	V _C	I _{PP} =10A,t _p =8/20μs			15	V
JunctionCapacitance	Cj	$V_R = 0V$, $f = 1MHz$ (pin1, pin2 to pin3)		100		pF

Electrical Parameters (TA = 25°C unless otherwisenoted)

Symbol	Parameter
Ірр	Maximum Reverse Peak Pulse Current
Vc	Clamping Voltage @ Ipp
V _{RW M}	Working Peak Reverse Voltage
IR	Maximum Reverse Leakage Current @ VRW M
V_{BR}	Breakdown Voltage @ IT
Iт	Test Current



Note:. $8/20\mu s$ pulsewaveform.



TypicalCharacteristics

Figure 1: Peak Pulse Power vs. Pulse Time

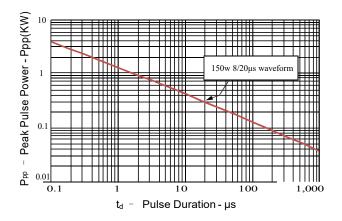


Figure 2: Power Derating Curve

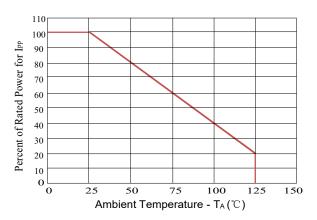


Figure3: Pulse Waveform

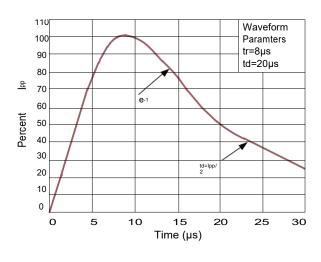
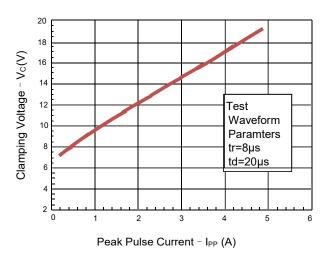
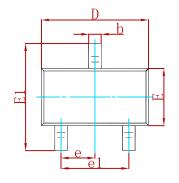


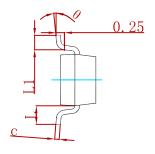
Figure 4: Clamping Voltage vs.lpp

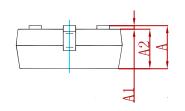




PACKAGE MECHANICAL DATA

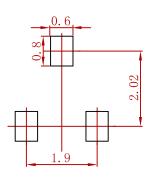






Cumbal	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min	Max	Min	Max
Α	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
С	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
Е	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
е	0.950) TYP	0.037	7 TYP
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

Suggested Pad Layout



- 1.Controlling dimension:in millimeters.2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
ESDA6V1L	SOT-23	3000



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